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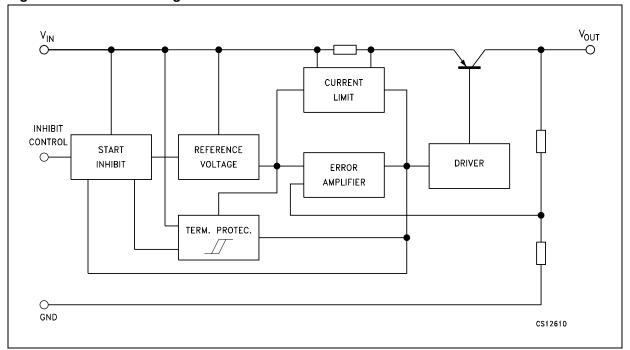
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KFxxB Diagram

1 Diagram

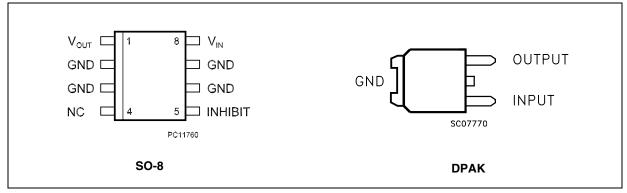
Figure 1. Schematic diagram



Pin configuration KFxxB

2 Pin configuration

Figure 2. Pin connections (top view)



KFxxB Maximum ratings

3 Maximum ratings

 Table 2.
 Absolute maximum ratings

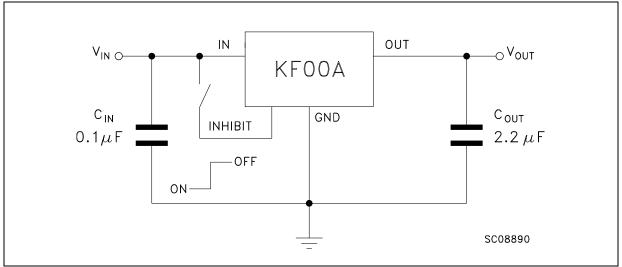
Symbol	Parameter	Value	Unit
VI	DC input voltage	-0.5 to 20	V
I _O	Output current	Internally Limited	
P _{TOT}	Power dissipation	Internally Limited	
T _{STG}	Storage temperature range	-40 to 150	°C
T _{OP}	Operating junction temperature range	-40 to 125	°C

Note: Absolute maximum ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

Table 3. Thermal data

Symbol	Parameter	DPAK	SO-8	Unit
R_{thJC}	Thermal resistance junction-case	8	20	°C/W

Figure 3. Test circuit



Electrical characteristics KFxxB

4 Electrical characteristics

Table 4. Electrical characteristics for KF15 (refer to the test circuits, T_J = 25 °C, C_I = 0.1 μF, C_O = 2.2 μF unless otherwise specified.)

Symbol	Parameter	Test condition	s	Min.	Тур.	Max.	Unit
\/	Output valtage	$I_O = 50 \text{ mA}, V_I = 3.5 \text{ V}$		1.47	1.5	1.53	V
V _O	Output voltage	$I_O = 50 \text{ mA}, V_I = 3.5 \text{ V}, T_a =$	$I_O = 50 \text{ mA}, V_I = 3.5 \text{ V}, T_a = -25 \text{ to } 85^{\circ}\text{C}$			1.56	V
VI	Operating input voltage	I _O = 500 mA		2.5		20	V
Io	Output current limit				1		Α
ΔV_{O}	Line regulation	$V_{I} = 2.5 \text{ to } 20 \text{ V}, I_{O} = 5 \text{ mA}$			2	12	mV
ΔV_{O}	Load regulation	$V_I = 2.8 \text{ V}, I_O = 5 \text{ to } 500 \text{ mA}$	ı		2	50	mV
		$V_{I} = 2.5 \text{ to } 20V, I_{O} = 0\text{mA}$	ON MODE		0.5	1	
I_{d}	Quiescent current	$V_{I} = 2.8 \text{ to } 20V, I_{O} = 500 \text{mA}$				12	mA
	V _I = 6 V OFF MODE		50	100	μΑ		
		f = 120 Hz		82			
SVR	Supply voltage rejection	$I_O = 5 \text{ mA}, V_I = 3.5 \pm 1 \text{ V}$	f = 1 kHz		77		dB
			f = 10 kHz		60		
eN	Output noise voltage	B = 10 Hz to 100 kHz	•		50		μV
V_d	Dropout voltage	I _O = 200 mA			1		V
V_{IL}	Control input logic low	$T_a = -40 \text{ to } 125^{\circ}\text{C}$				0.8	V
V_{IH}	Control input logic high	$T_a = -40 \text{ to } 125^{\circ}\text{C}$		2			V
I _I	Control input current	$V_{I} = 6 \text{ V}, V_{C} = 6 \text{ V}$	V _I = 6 V, V _C = 6 V		10		μΑ
C _O	Output bypass capacitance	ESR = 0.1 to 10 Ω , $I_0 = 0$ to	500 mA	2	10		μF

Table 5. Electrical characteristics for KF25 (refer to the test circuits, T_J = 25 °C, C_I = 0.1 μF, C_O = 2.2 μF unless otherwise specified.)

Symbol	Parameter	Test condition	ıs	Min.	Тур.	Max.	Unit
V	Output voltage	I _O = 50 mA, V _I = 4.5 V		2.45	2.5	2.55	V
V _O	Output voltage	$I_O = 50 \text{ mA}, V_I = 4.5 \text{ V}, T_a =$	= -25 to 85°C	2.4		2.6	V
VI	Operating input voltage	I _O = 500 mA				20	V
Io	Output current limit				1		Α
ΔV_{O}	Line regulation	$V_1 = 3.5 \text{ to } 20 \text{ V}, I_0 = 5 \text{ mA}$			2	12	mV
ΔV_{O}	Load regulation	$V_1 = 3.8 \text{ V}, I_0 = 5 \text{ to } 500 \text{ mA}$	1		2	50	mV
		$V_1 = 3.5 \text{ to } 20V, I_0 = 0\text{mA}$	ON MODE		0.5	1	Л
I_d	Quiescent current	$V_1 = 3.8 \text{ to } 20V, I_0 = 500\text{mA}$				12	mA
		V _I = 6 V	OFF MODE		50	100	μΑ
		f = 120 Hz		82			
SVR	Supply voltage rejection	$I_O = 5 \text{ mA}, V_I = 4.5 \pm 1 \text{ V}$	f = 1 kHz		77		dB
			f = 10 kHz		60		
eN	Output noise voltage	B = 10 Hz to 100 KHz	1		50		μV
	Donastick	I _O = 200 mA			0.2	0.35	\ /
V_d	Dropout voltage	I _O = 500 mA			0.4	0.7	V
V_{IL}	Control input logic low	T _a = -40 to 125°C				0.8	٧
V _{IH}	Control input logic high	$T_a = -40 \text{ to } 125^{\circ}\text{C}$	T _a = -40 to 125°C				٧
l _l	Control input current	V _I = 6 V, V _C = 6 V			10		μA
C _O	Output bypass capacitance	ESR = 0.1 to 10 Ω , $I_0 = 0$ to	500 mA	2	10		μF

Electrical characteristics KFxxB

Table 6. Electrical characteristics for KF30 (refer to the test circuits, T_J = 25 °C, C_I = 0.1 μF, C_O = 2.2 μF unless otherwise specified.)

Symbol	Parameter	Test condition	s	Min.	Тур.	Max.	Unit
V.	Output voltage	I _O = 50 mA, V _I = 5 V		2.94	3	3.06	V
Vo	Output voltage	$I_0 = 50 \text{ mA}, V_1 = 5 \text{ V}, T_a = -$	$I_O = 50 \text{ mA}, V_I = 5 \text{ V}, T_a = -25 \text{ to } 85^{\circ}\text{C}$			3.12	v
V _I	Operating input voltage	I _O = 500 mA				20	V
Io	Output current limit				1		Α
ΔV_{O}	Line regulation	$V_1 = 4 \text{ to } 20 \text{ V}, I_0 = 5 \text{ mA}$			2	12	mV
ΔV _O	Load regulation	$V_1 = 4.3 \text{ V}, I_0 = 5 \text{ to } 500 \text{ mA}$	ı		2	50	mV
		V _I = 4 to 20V, I _O = 0mA	ON MODE		0.5	1	Л
I_{d}	Quiescent current	$V_{I} = 4.3 \text{ to } 20V, I_{O} = 500 \text{mA}$	ON WODE			12	mA
	V _I = 6 V OFF MODE		50	100	μΑ		
		f	f = 120 Hz		81		
SVR	Supply voltage rejection	$I_{O} = 5 \text{ mA}, V_{I} = 5 \pm 1 \text{ V}$	f = 1 kHz		76		dB
			f = 10 kHz		60		
eN	Output noise voltage	B = 10 Hz to 100 KHz			50		μV
M	Dranavitualtaria	I _O = 200 mA			0.2	0.35	V
V_d	Dropout voltage	I _O = 500 mA			0.4	0.7	V
V_{IL}	Control input logic low	$T_a = -40 \text{ to } 125^{\circ}\text{C}$				0.8	V
V _{IH}	Control input logic high	$T_a = -40 \text{ to } 125^{\circ}\text{C}$	T _a = -40 to 125°C				V
I _I	Control input current	$V_{I} = 6 \text{ V}, V_{C} = 6 \text{ V}$	V _I = 6 V, V _C = 6 V		10		μΑ
Co	Output bypass capacitance	ESR = 0.1 to 10 Ω , $I_0 = 0$ to	500 mA	2	10		μF

Table 7. Electrical characteristics for KF33 (refer to the test circuits, T_J = 25 °C, C_I = 0.1 μF, C_O = 2.2 μF unless otherwise specified.)

Symbol	Parameter	Test condition	ıs	Min.	Тур.	Max.	Unit
\/	Output voltage	$I_O = 50 \text{ mA}, V_I = 5.3 \text{ V}$		3.234	3.3	3.366	V
V _O	Output voltage	$I_O = 50 \text{ mA}, V_I = 5.3 \text{ V}, T_a =$	25 to 85°C	3.168		3.432	V
V _I	Operating input voltage	I _O = 500 mA				20	V
Io	Output current limit				1		Α
ΔV_{O}	Line regulation	$V_1 = 4.3 \text{ to } 20 \text{ V}, I_0 = 5 \text{ mA}$			2	12	mV
ΔV_{O}	Load regulation	$V_1 = 4.6 \text{ V}, I_0 = 5 \text{ to } 500 \text{ mA}$	Ĺ		2	50	mV
		$V_{I} = 4.3 \text{ to } 20V, I_{O} = 0\text{mA}$	ON MODE		0.5	1	Л
I_{d}	Quiescent current	V _I = 4.6 to 20V, I _O =500mA				12	mA
		V _I = 6 V	OFF MODE		50	100	μΑ
			f = 120 Hz		80		
SVR	Supply voltage rejection	$I_{O} = 5 \text{ mA}, V_{I} = 5.3 \pm 1 \text{ V}$	f = 1 kHz		75		dB
			f = 10 kHz		60		
eN	Output noise voltage	B = 10 Hz to 100 KHz			50		μV
V	Dranautwaltana	I _O = 200 mA			0.2	0.35	V
V_d	Dropout voltage	I _O = 500 mA			0.4	0.7	V
V _{IL}	Control input logic low	$T_a = -40 \text{ to } 125^{\circ}\text{C}$				0.8	٧
V _{IH}	Control input logic high	$T_a = -40 \text{ to } 125^{\circ}\text{C}$		2			V
I _I	Control input current	$V_{I} = 6 \text{ V}, V_{C} = 6 \text{ V}$			10		μΑ
Co	Output bypass capacitance	ESR = 0.1 to 10 Ω , $I_0 = 0$ to	500 mA	2	10		μF

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Electrical characteristics KFxxB

Table 8. Electrical characteristics for KF40 (refer to the test circuits, T_J = 25 °C, C_I = 0.1 μF, C_O = 2.2 μF unless otherwise specified.)

Symbol	Parameter	Test condition	s	Min.	Тур.	Max.	Unit
V.	Output voltage	I _O = 50 mA, V _I = 6 V		3.92	4	4.08	V
Vo	Output voltage	$I_0 = 50 \text{ mA}, V_1 = 6 \text{ V}, T_a = -$	$I_O = 50 \text{ mA}, V_I = 6 \text{ V}, T_a = -25 \text{ to } 85^{\circ}\text{C}$			4.16	v
VI	Operating input voltage	I _O = 500 mA				20	V
Io	Output current limit				1		Α
ΔV _O	Line regulation	$V_1 = 5 \text{ to } 20 \text{ V}, I_0 = 5 \text{ mA}$			3	18	mV
ΔV _O	Load regulation	$V_1 = 5.3 \text{ V}, I_0 = 5 \text{ to } 500 \text{ mA}$	ı		2	50	mV
		V _I = 5 to 20V, I _O = 0mA	ON MODE		0.5	1	Л
I_{d}	Quiescent current	$V_{I} = 5.3 \text{ to } 20V, I_{O} = 500 \text{mA}$	A			12	mA
	V _I = 6 V OFF MODE		50	100	μΑ		
		f =	f = 120 Hz		78		
SVR	Supply voltage rejection	$I_0 = 5 \text{ mA}, V_1 = 6 \pm 1 \text{ V}$	f = 1 kHz		73		dB
			f = 10 kHz		60		
eN	Output noise voltage	B = 10 Hz to 100 KHz			50		μV
M	Dranavitualtaria	I _O = 200 mA			0.2	0.35	V
V_d	Dropout voltage	I _O = 500 mA			0.4	0.7	V
V_{IL}	Control input logic low	$T_a = -40 \text{ to } 125^{\circ}\text{C}$				0.8	V
V _{IH}	Control input logic high	$T_a = -40 \text{ to } 125^{\circ}\text{C}$	T _a = -40 to 125°C				V
I _I	Control input current	$V_{I} = 6 \text{ V}, V_{C} = 6 \text{ V}$			10		μΑ
Co	Output bypass capacitance	ESR = 0.1 to 10 Ω , $I_0 = 0$ to	500 mA	2	10		μF

Table 9. Electrical characteristics for KF50 (refer to the test circuits, T_J = 25 °C, C_I = 0.1 μF, C_O = 2.2 μF unless otherwise specified.)

Symbol	Parameter	Test condition	ıs	Min.	Тур.	Max.	Unit	
V.	Output voltage	$I_O = 50 \text{ mA}, V_I = 7 \text{ V}$		4.9	5	5.1	V	
V _O	Output voltage	$I_O = 50 \text{ mA}, V_I = 7 \text{ V}, T_a = -$	25 to 85°C	4.8		5.2	V	
VI	Operating input voltage	I _O = 500 mA				20	V	
Io	Output current limit				1		Α	
ΔV_{O}	Line regulation	V _I = 6 to 20 V, I _O = 5 mA			3	18	mV	
ΔV_{O}	Load regulation	$V_{I} = 6.3 \text{ V}, I_{O} = 5 \text{ to } 500 \text{ mA}$	1		2	50	mV	
		V _I = 6 to 20V, I _O = 0mA	ONLMODE		0.5	1	Л	
I_d	Quiescent current $V_I = 6.3 \text{ to } 20\text{V}, I_O = 500\text{mA}$ $V_I = 6 \text{ V}$ OFF MODE	$V_1 = 6.3 \text{ to } 20V, I_0 = 500 \text{mA}$	ON MODE			12	mA	
			50	100	μΑ			
			f = 120 l	f = 120 Hz		76		
SVR	Supply voltage rejection	$I_{O} = 5 \text{ mA}, V_{I} = 7 \pm 1 \text{ V}$	f = 1 kHz		71		dB	
			f = 10 kHz		60			
eN	Output noise voltage	B = 10 Hz to 100 KHz			50		μV	
\/	Duanautwaltana	I _O = 200 mA			0.2	0.35	V	
V_d	Dropout voltage	I _O = 500 mA			0.4	0.7	V	
V _{IL}	Control input logic low	$T_a = -40 \text{ to } 125^{\circ}\text{C}$				0.8	V	
V _{IH}	Control input logic high	T _a = -40 to 125°C		2			V	
I _I	Control input current	$V_{I} = 6 \text{ V}, V_{C} = 6 \text{ V}$			10		μΑ	
C _O	Output bypass capacitance	ESR = 0.1 to 10 Ω , $I_0 = 0$ to	500 mA	2	10		μF	

Electrical characteristics KFxxB

Table 10. Electrical characteristics for KF52 (refer to the test circuits, T_J = 25 °C, C_I = 0.1 μF, C_O = 2.2 μF unless otherwise specified.)

Symbol	Parameter	Test condition	ıs	Min.	Тур.	Max.	Unit
V	Output voltage	$I_O = 50 \text{ mA}, V_I = 7.2 \text{ V}$		5.096	5.2	5.304	V
Vo	Output voltage	$I_O = 50 \text{ mA}, V_I = 7.2 \text{ V}, T_a = 0.0 \text{ mA}$	$_{\rm O}$ = 50 mA, $_{\rm I}$ = 7.2 V, $_{\rm a}$ = -25 to 85°C			5.408	V
VI	Operating input voltage	I _O = 500 mA				20	V
Io	Output current limit				1		Α
ΔV _O	Line regulation	$V_{I} = 6.2 \text{ to } 20 \text{ V}, I_{O} = 5 \text{ mA}$			3	18	mV
ΔV _O	Load regulation	$V_1 = 6.5 \text{ V}, I_0 = 5 \text{ to } 500 \text{ mA}$	1		2	50	mV
		$V_{I} = 6.2 \text{ to } 20V, I_{O} = 0\text{mA}$	ON MODE		0.5	1	А
I_d	Quiescent current	$V_{I} = 6.5 \text{ to } 20V, I_{O} = 500 \text{mA}$	ON MODE			12	mA
		V _I = 6 V OFF MODE		50	100	μA	
		f = 120 Hz		76			
SVR		f = 1 kHz		71		dB	
			f = 10 kHz		60		
eN	Output noise voltage	B = 10 Hz to 100 KHz			50		μV
M	Duranturaltana	I _O = 200 mA			0.2	0.35	
V_d	Dropout voltage	I _O = 500 mA			0.4	0.7	V
V_{IL}	Control input logic low	$T_a = -40 \text{ to } 125^{\circ}\text{C}$				0.8	٧
V _{IH}	Control input logic high	$T_a = -40 \text{ to } 125^{\circ}\text{C}$	T _a = -40 to 125°C				V
I _I	Control input current	$V_{I} = 6 \text{ V}, V_{C} = 6 \text{ V}$	V _I = 6 V, V _C = 6 V		10		μA
Co	Output bypass capacitance	ESR = 0.1 to 10 Ω , $I_0 = 0$ to	500 mA	2	10		μF

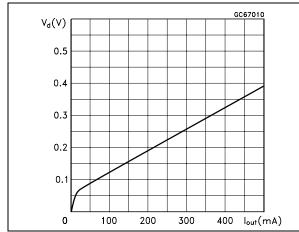
Table 11. Electrical characteristics for KF80 (refer to the test circuits, T_J = 25 °C, C_I = 0.1 μF, C_O = 2.2 μF unless otherwise specified.)

Symbol	Parameter	Test condition	ıs	Min.	Тур.	Max.	Unit
\/	Output voltage	I _O = 50 mA, V _I = 10 V		7.84	8	8.16	V
V _O	Output voltage	$I_O = 50 \text{ mA}, V_I = 10 \text{ V}, T_a =$	-25 to 85°C	7.68		8.32	V
VI	Operating input voltage	I _O = 500 mA				20	V
Io	Output current limit				1		Α
ΔV_{O}	Line regulation	$V_{I} = 9 \text{ to } 20 \text{ V}, I_{O} = 5 \text{ mA}$			4	24	mV
ΔV_{O}	Load regulation	$V_1 = 9.3 \text{ V}, I_0 = 5 \text{ to } 500 \text{ mA}$	1		2	50	mV
		V _I = 9 to 20V, I _O = 0mA	ON MODE		0.7	1.5	A
I_{d}	Quiescent current	$V_1 = 9.3 \text{ to } 20V, I_0 = 500 \text{mA}$				12	mA
		V _I = 9 V			70	140	μA
			f = 120 Hz		72		
SVR	Supply voltage rejection	$I_{O} = 5 \text{ mA}, V_{I} = 10 \pm 1 \text{ V}$	f = 1 kHz		67		dB
			f = 10 kHz		60		
eN	Output noise voltage	B = 10 Hz to 100 KHz			50		μV
V	Dunantualtana	I _O = 200 mA			0.2	0.35	V
V_d	Dropout voltage	I _O = 500 mA			0.4	0.7	V
V _{IL}	Control input logic low	T _a = -40 to 125°C				0.8	٧
V _{IH}	Control input logic high	T _a = -40 to 125°C	T _a = -40 to 125°C				V
I _I	Control input current	$V_{I} = 6 \text{ V}, V_{C} = 6 \text{ V}$	V _I = 6 V, V _C = 6 V		10		μΑ
C _O	Output bypass capacitance	ESR = 0.1 to 10 Ω , $I_0 = 0$ to	500 mA	2	10		μF

5 Typical performance characteristics

(unless otherwise specified $V_{O(NOM)} = 3.3 \text{ V}$)

Figure 4. Dropout voltage vs output current Figure 5. Dropout voltage vs temperature



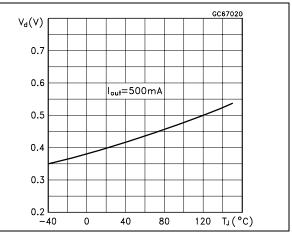


Figure 6. Supply current vs input voltage

16 | I_{out}=500mA | 12 | 8 | 4 | 0 | 0 | 4 | 8 | 12 | 16 | V_i(V)

Figure 7. Supply current vs input voltage

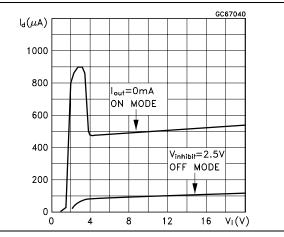
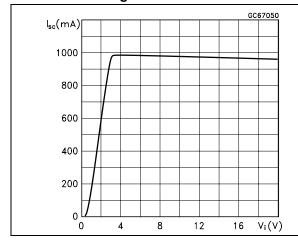
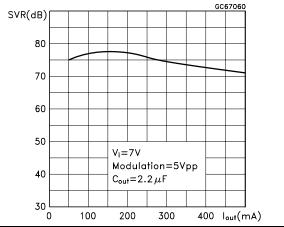


Figure 8. Short circuit current vs input voltage

Figure 9. Supply current vs temperature





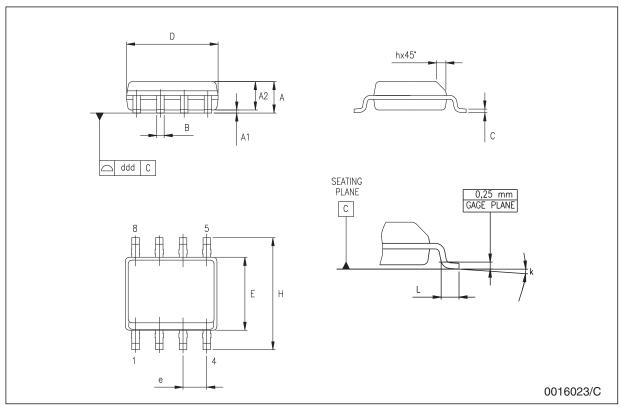
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6 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK[®] packages. These packages have a lead-free second level interconnect. The category of second Level Interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

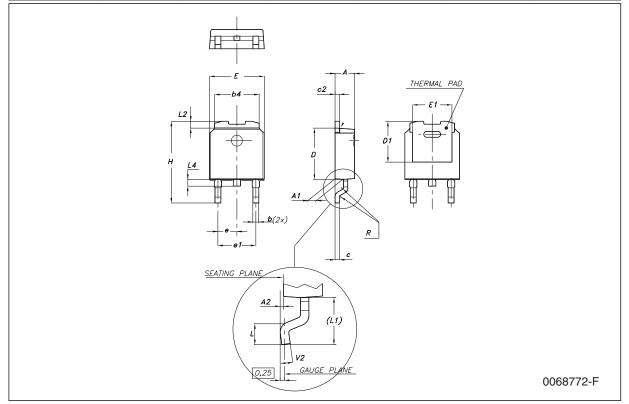
SO-8 mechanical data

Dim.		mm.		inch.			
Dilli.	Min.	Тур.	Max.	Min.	Тур.	Max.	
А	1.35		1.75	0.053		0.069	
A1	0.10		0.25	0.04		0.010	
A2	1.10		1.65	0.043		0.065	
В	0.33		0.51	0.013		0.020	
С	0.19		0.25	0.007		0.010	
D	4.80		5.00	0.189		0.197	
Е	3.80		4.00	0.150		0.157	
е		1.27			0.050		
Н	5.80		6.20	0.228		0.244	
h	0.25		0.50	0.010		0.020	
L	0.40		1.27	0.016		0.050	
k			8° (n	(max.)			
ddd			0.1			0.04	



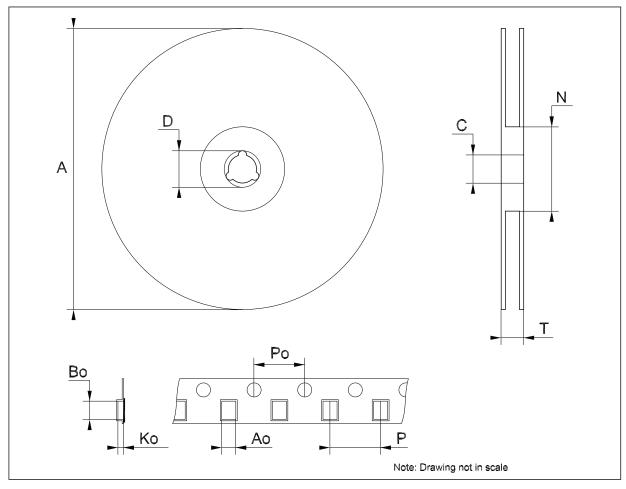
DPAK mechanical data

Dim.	mm.			inch.		
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	2.2		2.4	0.086		0.094
A1	0.9		1.1	0.035		0.043
A2	0.03		0.23	0.001		0.009
В	0.64		0.9	0.025		0.035
b4	5.2		5.4	0.204		0.212
С	0.45		0.6	0.017		0.023
C2	0.48		0.6	0.019		0.023
D	6		6.2	0.236		0.244
D1		5.1			0.200	
E	6.4		6.6	0.252		0.260
E1		4.7			0.185	
е		2.28			0.090	
e1	4.4		4.6	0.173		0.181
Н	9.35		10.1	0.368		0.397
L	1			0.039		
(L1)		2.8			0.110	
L2		0.8			0.031	
L4	0.6		1	0.023		0.039
R		0.2			0.008	
V2	0°		8°	0°		8°

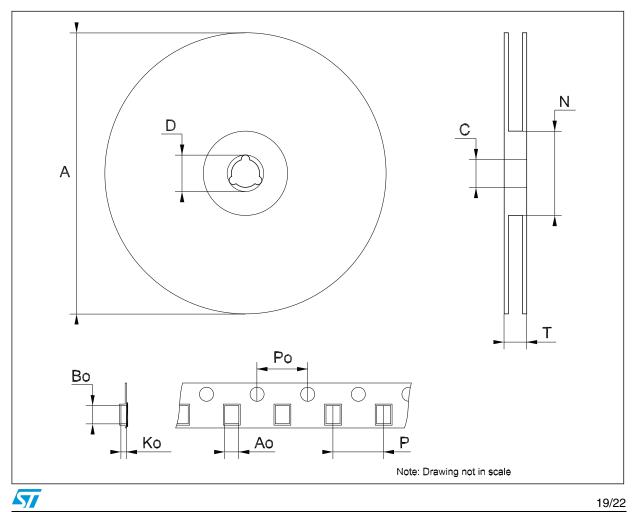


Tape & reel SO-8 mechanical data

Dim.	mm.			inch.		
	Min.	Тур.	Max.	Min.	Тур.	Max.
А			330			12.992
С	12.8		13.2	0.504		0.519
D	20.2			0.795		
N	60			2.362		
Т			22.4			0.882
Ao	8.1		8.5	0.319		0.335
Во	5.5		5.9	0.216		0.232
Ko	2.1		2.3	0.082		0.090
Ро	3.9		4.1	0.153		0.161
Р	7.9		8.1	0.311		0.319



Dim.	mm.			inch.		
	Min.	Тур.	Max.	Min.	Тур.	Max.
А			330			12.992
С	12.8	13.0	13.2	0.504	0.512	0.519
D	20.2			0.795		
N	60			2.362		
Т			22.4			0.882
Ao	6.80	6.90	7.00	0.268	0.272	0.2.76
Во	10.40	10.50	10.60	0.409	0.413	0.417
Ko	2.55	2.65	2.75	0.100	0.104	0.105
Po	3.9	4.0	4.1	0.153	0.157	0.161
Р	7.9	8.0	8.1	0.311	0.315	0.319



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Order codes KFxxB

7 Order codes

Table 12. Order codes

Pack	Output valtage		
SO-8 (Tape and reel)	DPAK (Tape and reel)	Output voltage	
	KF15BDT-TR	1.5 V	
KF25BD-TR	KF25BDT-TR	2.5 V	
KF30BD-TR		3 V	
KF33BD-TR	KF33BDT-TR	3.3 V	
KF40BD-TR	KF40BDT-TR	4 V	
KF50BD-TR	KF50BDT-TR	5 V	
KF52BD-TR		5.2 V	
KF80BD-TR	KF80BDT-TR	8 V	

KFxxB Revision history

8 Revision history

Table 13. Document revision history

Date	Revision	Changes
06-Jun-2007	9	Order codes has been updated and the document has been reformatted.
14-Dec-2007	10	Modified: Table 12.

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